

NTJD1155L

Power MOSFET

8 V, ± 1.3 A, High Side Load Switch with Level-Shift, P-Channel SC-88

The NTJD1155L integrates a P and N-Channel MOSFET in a single package. This device is particularly suited for portable electronic equipment where low control signals, low battery voltages and high load currents are needed. The P-Channel device is specifically designed as a load switch using ON Semiconductor state-of-the-art trench technology. The N-Channel, with an external resistor (R1), functions as a level-shift to drive the P-Channel. The N-Channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The NTJD1155L operates on supply lines from 1.8 to 8.0 V and can drive loads up to 1.3 A with 8.0 V applied to both V_{IN} and $V_{ON/OFF}$.

Features

- Extremely Low $R_{DS(on)}$ P-Channel Load Switch MOSFET
- Level Shift MOSFET is ESD Protected
- Low Profile, Small Footprint Package
- V_{IN} Range 1.8 to 8.0 V
- ON/OFF Range 1.5 to 8.0 V
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating		Symbol	Value	Unit
Input Voltage (V_{DSS} , P-Ch)		V_{IN}	8.0	V
ON/OFF Voltage (V_{GS} , N-Ch)		$V_{ON/OFF}$	8.0	V
Continuous Load Current (Note 1)	Steady State	I_L	± 1.3	A
			± 0.9	
Power Dissipation (Note 1)	Steady State	P_D	0.40	W
			0.20	
Pulsed Load Current	$t_p = 10 \mu\text{s}$	I_{LM}	± 3.9	A
Operating Junction and Storage Temperature		T_J , T_{STG}	-55 to 150	$^\circ\text{C}$
Source Current (Body Diode)		I_S	-0.4	A
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		T_L	260	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Junction-to-Ambient – Steady State (Note 1)	$R_{\theta JA}$	320	$^\circ\text{C/W}$
Junction-to-Foot – Steady State (Note 1)	$R_{\theta JF}$	220	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Surface-mounted on FR4 board using 1 inch sq pad size (Cu area = 1.127 in sq [1 oz] including traces).

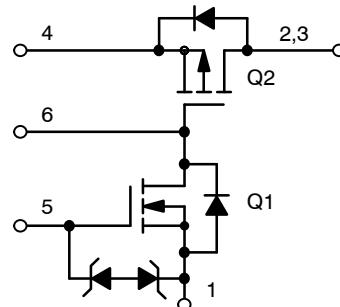


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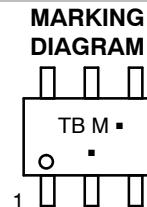
<http://onsemi.com>

$V_{(BR)DSS}$	$R_{DS(on)}$ TYP	I_D MAX
8.0 V	130 m Ω @ -4.5 V	
	170 m Ω @ -2.5 V	± 1.3 A
	260 m Ω @ -1.8 V	

SIMPLIFIED SCHEMATIC

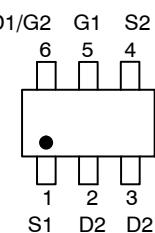


SC-88
(SOT-363)
CASE 419B
STYLE 30



TB = Device Code
M = Date Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)

PIN ASSIGNMENT



ORDERING INFORMATION

Device	Package	Shipping [†]
NTJD1155LT1G	SC-88 (Pb-Free)	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NTJD1155L

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Test Condition		Min	Typ	Max	Unit
OFF CHARACTERISTICS							
Q2 Drain-to-Source Breakdown Voltage	V_{IN}	$V_{GS2} = 0 \text{ V}$, $I_{D2} = 250 \mu\text{A}$		-8.0			V
Forward Leakage Current	I_{FL}	$V_{GS1} = 0 \text{ V}$, $V_{DS2} = -8.0 \text{ V}$	$T_J = 25^\circ\text{C}$		1.0		μA
			$T_J = 125^\circ\text{C}$		10		
Q1 Gate-to-Source Leakage Current	I_{GSS}	$V_{DS1} = 0 \text{ V}$, $V_{GS1} = \pm 8.0 \text{ V}$			± 100	nA	
Q1 Diode Forward On-Voltage	V_{SD}	$I_S = -0.4 \text{ A}$, $V_{GS1} = 0 \text{ V}$			-0.8	-1.1	V
ON CHARACTERISTICS							
ON/OFF Voltage	$V_{ON/OFF}$			1.5		8.0	V
Q1 Gate Threshold Voltage	$V_{GS1(\text{th})}$	$V_{GS1} = V_{DS1}$, $I_D = 250 \mu\text{A}$		0.4		1.0	V
Input Voltage	V_{IN}	$V_{GS1} = V_{DS1}$, $I_D = 250 \mu\text{A}$		1.8		8.0	V
Q2 Drain-to-Source On Resistance	$R_{DS(\text{on})}$	$V_{ON/OFF} = 1.5 \text{ V}$	$V_{IN} = 4.5 \text{ V}$ $I_L = 1.2 \text{ A}$		130	175	$\text{m}\Omega$
			$V_{IN} = 2.5 \text{ V}$ $I_L = 1.0 \text{ A}$		170	220	
			$V_{IN} = 1.8 \text{ V}$ $I_L = 0.7 \text{ A}$		260	320	
Load Current	I_L	$V_{DROP} \leq 0.2 \text{ V}$, $V_{IN} = 5.0 \text{ V}$, $V_{ON/OFF} = 1.5 \text{ V}$		1.0			A
		$V_{DROP} \leq 0.3 \text{ V}$, $V_{IN} = 2.5 \text{ V}$, $V_{ON/OFF} = 1.5 \text{ V}$		1.0			

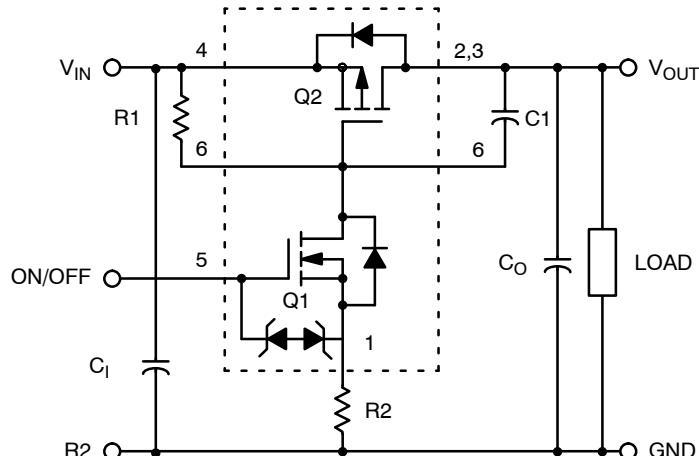


Figure 1. Load Switch Application

Components	Description	Values
R1	Pullup Resistor	Typical 10 k Ω to 1.0 M Ω *
R2	Optional Slew-Rate Control	Typical 0 to 100 k Ω *
C_O , C_I	Output Capacitance	Usually < 1.0 μF
C1	Optional In-Rush Current Control	Typical $\leq 1000 \text{ pF}$

*Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.

TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise noted)

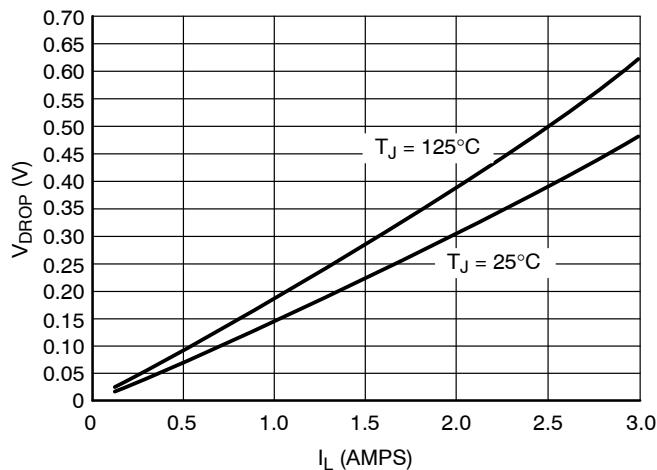


Figure 2. V_{drop} vs. I_L @ $V_{\text{in}} = 2.5$ V

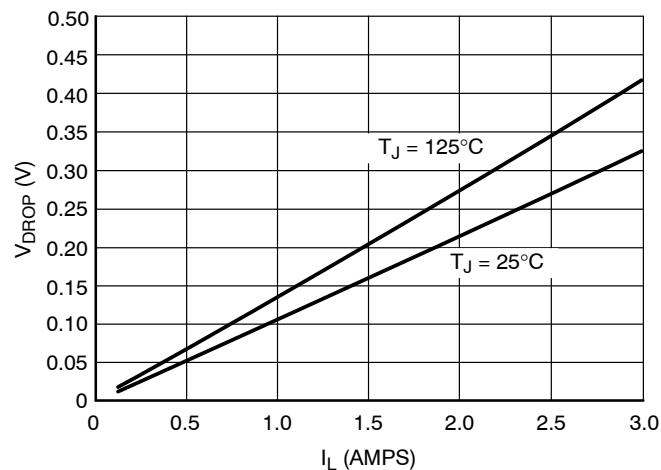


Figure 3. V_{drop} vs. I_L @ $V_{\text{in}} = 4.5$ V

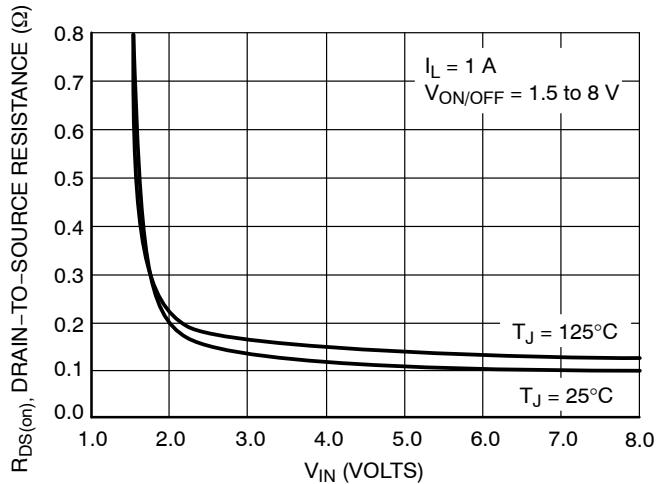


Figure 4. On-Resistance vs. Input Voltage

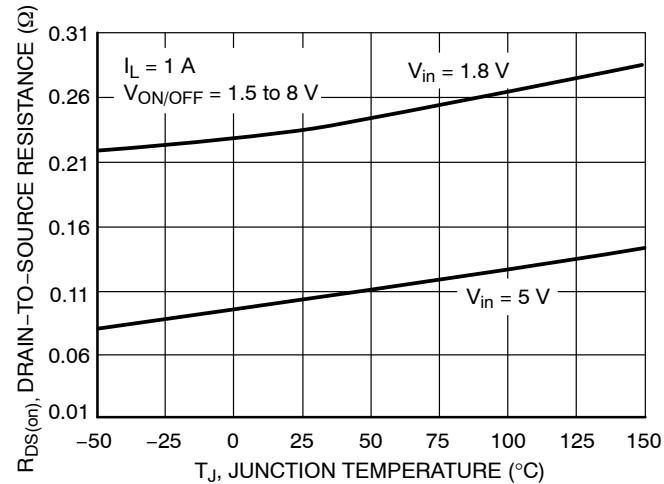


Figure 5. On-Resistance Variation with Temperature

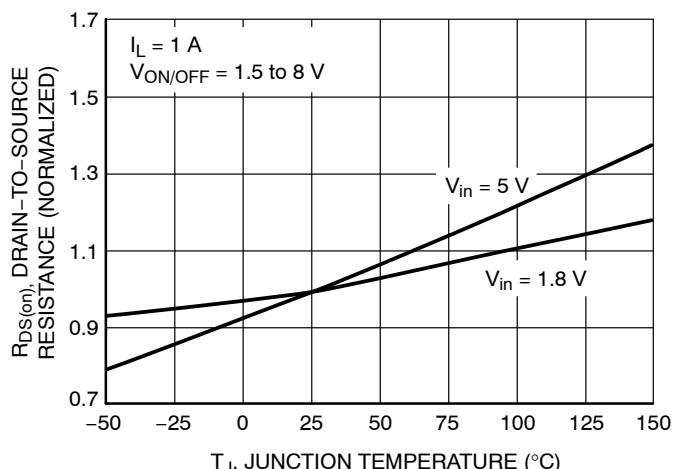


Figure 6. Normalized On-Resistance Variation with Temperature

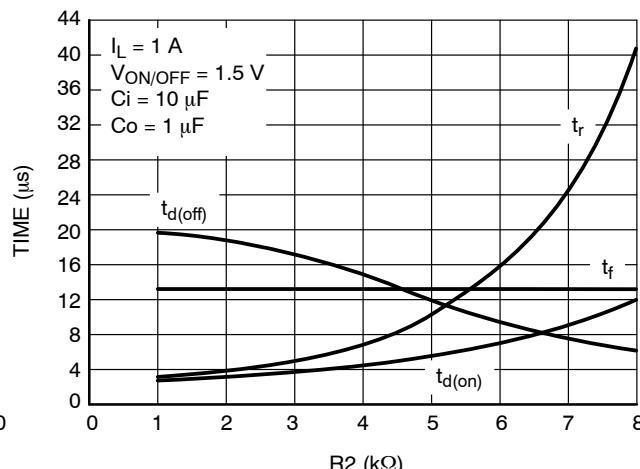


Figure 7. Switching Variation
R2 @ $V_{\text{in}} = 4.5$ V, $R1 = 20$ k Ω

NTJD1155L

TYPICAL PERFORMANCE CURVES ($T_J = 25^\circ\text{C}$ unless otherwise noted)

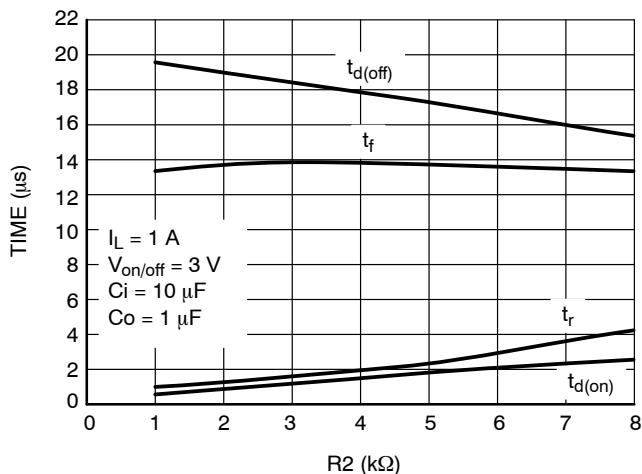


Figure 8. Switching Variation
 $R_2 @ V_{in} = 4.5 \text{ V}, R_1 = 20 \text{ k}\Omega$

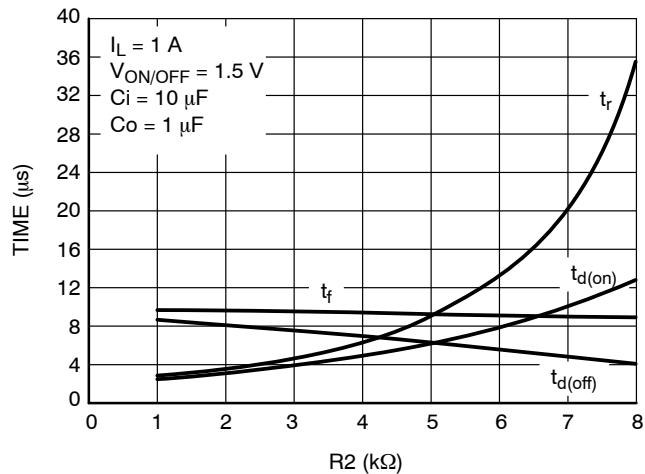


Figure 9. Switching Variation
 $R_2 @ V_{in} = 2.5 \text{ V}, R_1 = 20 \text{ k}\Omega$

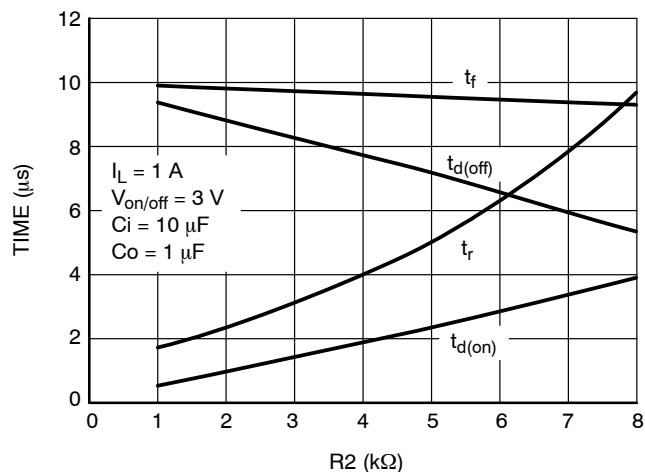


Figure 10. Switching Variation
 $R_2 @ V_{in} = 2.5 \text{ V}, R_1 = 1 \text{ k}\Omega$

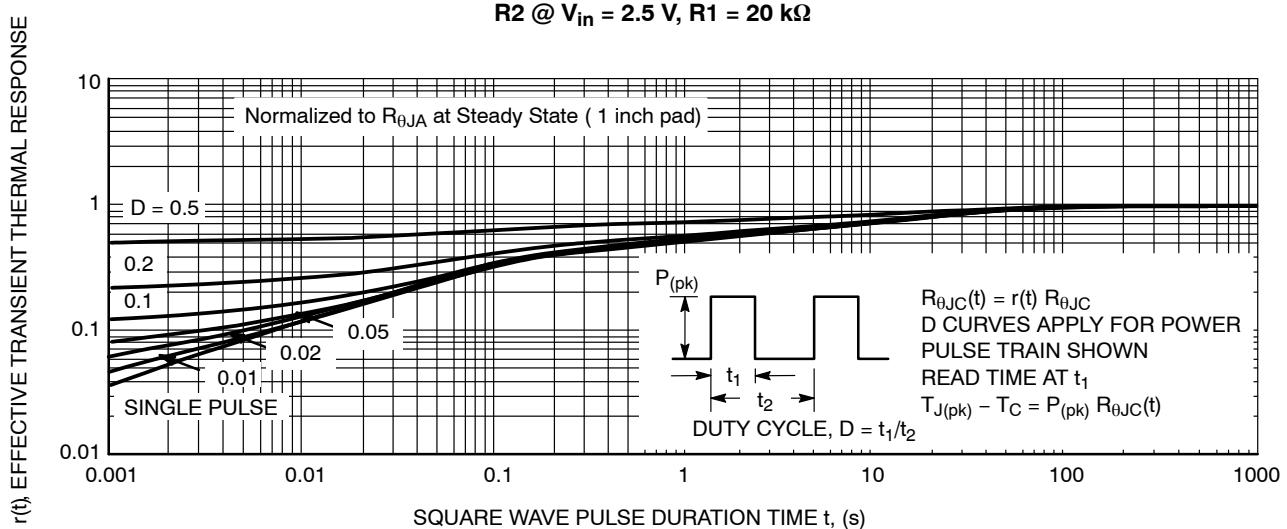


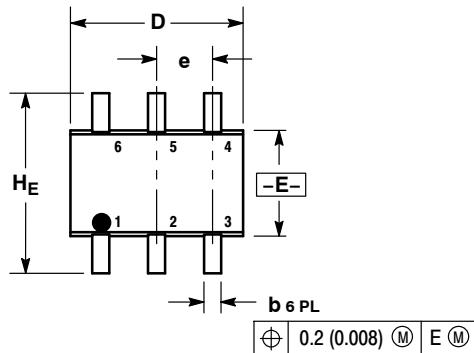
Figure 11. FET Thermal Response

PACKAGE DIMENSIONS

SC-88 (SOT-363)

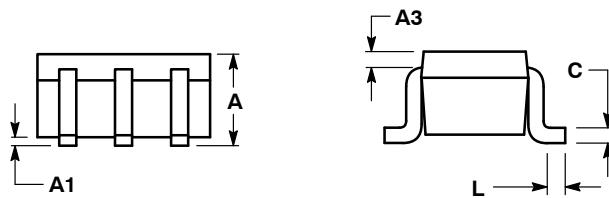
CASE 419B-02

ISSUE W



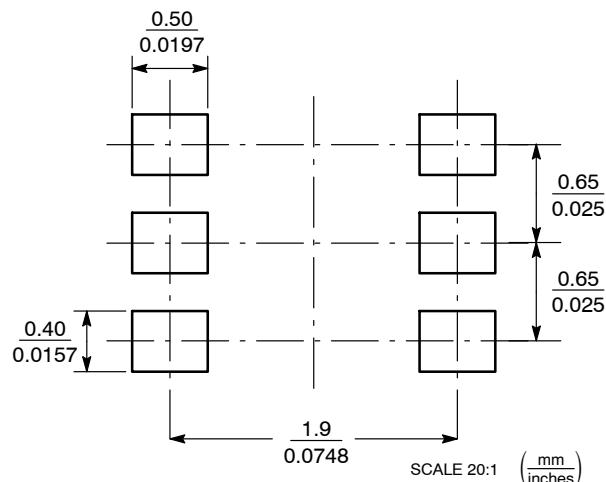
NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.20	REF		0.008	REF	
b	0.10	0.21	0.30	0.004	0.008	0.012
C	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65	BSC		0.026	BSC	
L	0.10	0.20	0.30	0.004	0.008	0.012
H _E	2.00	2.10	2.20	0.078	0.082	0.086



STYLE 30:
 PIN 1. SOURCE 1
 2. DRAIN 2
 3. DRAIN 2
 4. SOURCE 2
 5. GATE 1
 6. DRAIN 1

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERERRM/D.

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